

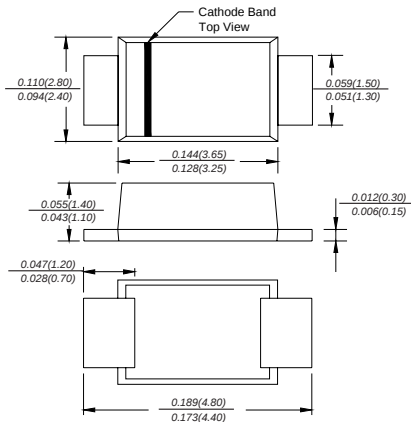


SS12F THRU SS1200F

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts Forward Current - 1.0 Ampere

SMAF



Dimensions in inches and (millimeters)

FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed: 260°C/10 seconds at terminals

MECHANICAL DATA

Case: JEDEC SMAF molded plastic body

Terminals: leads solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.0018 ounce, 0.064 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	SS12F	SS13F	SS14F	SS15F	SS16F	SS18F	SS110F	SS1150F	SS1200F	UNITS
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	150	200	VOLTS
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	105	140	VOLTS
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	150	200	VOLTS
Maximum average forward rectified current at T _L (see fig.1)	I _(AV)	1.0									Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	30.0									Amps
Maximum instantaneous forward voltage at 1.0A	V _F	0.55			0.70			0.85		0.95	Volts
Maximum DC reverse current T _A =25°C at rated DC blocking voltage T _A =100°C	I _R	0.5						0.2		mA	
		10.0				5.0		2.0			
Typical junction capacitance (NOTE 1)	C _J	110			90						pF
Typical thermal resistance (NOTE 2)	R _{θJA}	88.0									°C/W
Operating junction temperature range	T _J	-50 to +125						-50 to +150			°C
Storage temperature range	T _{STG}	-50 to +150									°C

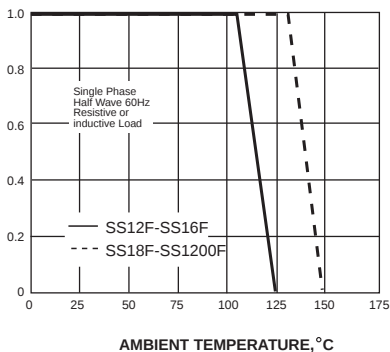
Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

RATINGS AND CHARACTERISTIC CURVES SS12F THRU SS1200F

AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT,
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

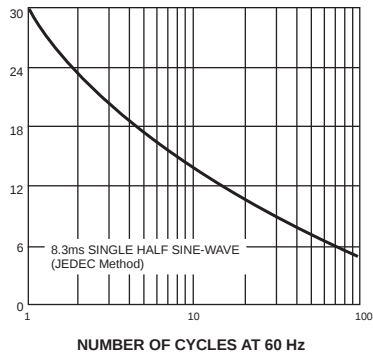
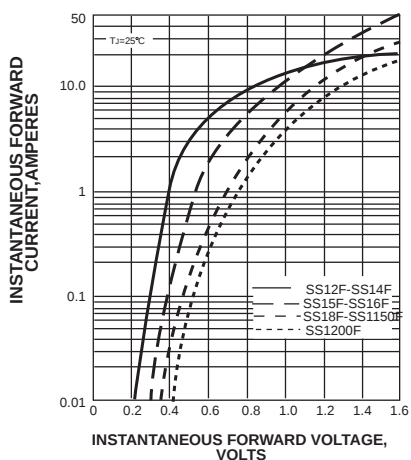


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS REVERSE CURRENT,
MILLIAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS

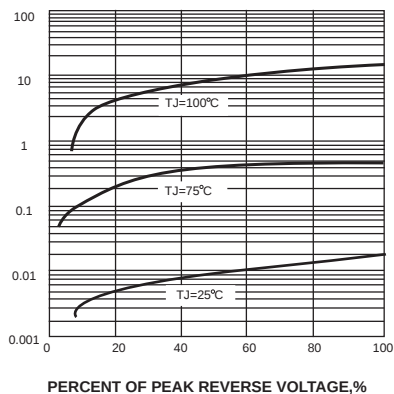
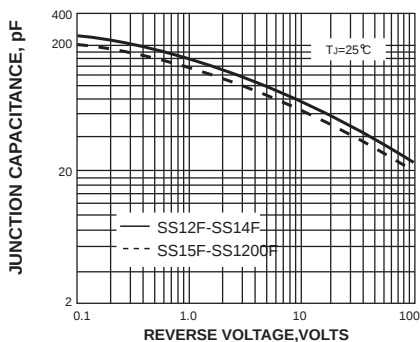


FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

